

TOSHIBA Diode Silicon Epitaxial Planar Type

1SS361F

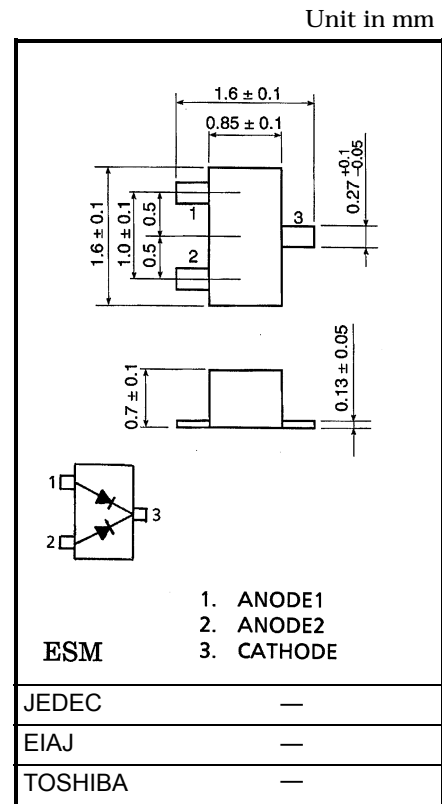
Ultra High Speed Switching Applications

- Small package : 1608 Flat lead
- Excellent in forward current and forward voltage characteristics : $V_F(3) = 0.9V$ (typ.)
- Fast reverse recovery time: $t_{rr} = 1.6ns$ (typ.)
- Small total capacitance : $C_T = 0.9pF$ (typ.)

Maximum Ratings (Ta = 25°C)

| Characteristic | Symbol | Rating | Unit |
|--------------------------------|-----------|---------|------|
| Maximum (peak) reverse voltage | V_{RM} | 85 | V |
| Reverse voltage | V_R | 80 | V |
| Maximum (peak) forward current | I_{FM} | 300 (*) | mA |
| Average forward current | I_O | 100 (*) | mA |
| Surge current (10ms) | I_{FSM} | 2 (*) | A |
| Power dissipation | P | 100 | mW |
| Junction temperature | T_j | 125 | °C |
| Storage temperature range | T_{stg} | -55~125 | °C |

(*) Unit rating. Total rating = unit rating × 1.5



Electrical Characteristics (Ta = 25°C)

| Characteristic | Symbol | Test Circuit | Test Condition | Min | Typ. | Max | Unit |
|-----------------------|----------|--------------|----------------------|-----|------|------|---------|
| Forward voltage | $V_F(1)$ | — | $I_F = 1mA$ | — | 0.60 | — | V |
| | $V_F(2)$ | — | $I_F = 10mA$ | — | 0.72 | — | |
| | $V_F(3)$ | — | $I_F = 100mA$ | — | 0.90 | 1.20 | |
| Reverse current | $I_R(1)$ | — | $V_R = 30V$ | — | — | 0.1 | μA |
| | $I_R(2)$ | — | $V_R = 80V$ | — | — | 0.5 | |
| Total capacitance | C_T | — | $V_R = 0, f = 1MHz$ | — | 0.9 | 3.0 | pF |
| Reverse recovery time | t_{rr} | — | $I_F = 10mA$ (Fig.1) | — | 1.6 | 4.0 | ns |

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Fig.1 Reverse Recovery Time (t_{rr}) Test Circuit

Marking

